

Photoswitchable Nanoelectronics based on 2D Materials and Photochromic Molecules

Light-programmable tuning of MoSe₂ devices using photochromic molecules to enable switchable phototransistors and adaptive optoelectronics.

Researchers at Purdue University have developed a facile strategy for modulating electronic band energies of the monolayer MoSe₂ with external light. Fine-tuning optical and electrical properties of two-dimensional (2D) semiconductors has sparked considerable interest in transition metal dichalcogenides (TMDs). Multiple approaches such as polarization switching and spin-valley tuning have been contrived to modulate charge transport in TMDs, but these tactics present challenges in manufacturing and characterization processes.

This method developed by Purdue University researchers generates a new class of photoswitchable nanoelectronics that preserve the unique characteristics of MoSe₂. The fabrication strategy can be leveraged to create versatile and multi-responsive optoelectronics, ultimately serving as an invaluable tool to program electronic devices. This new photo-control method helps expand the library of 2D material-based electronics and opens novel opportunities for designing new phototransistors and other 2D optoelectronic devices.

Related Publications: Park, S., Ji, J., Cunningham, C. et al. Photoswitchable optoelectronic properties of 2D MoSe₂/diarylethene hybrid structures. Sci Rep 14, 7325 (2024). <https://doi.org/10.1038/s41598-024-57479-z>

Technology Validation:

Ten cycles of photoluminescence (PL) modulation demonstrated photoswitchable optoelectronic properties of the monolayer MoSe₂ with photochromic diarylethene (DAE). Findings proved the viability of charge transport modulation on 2D semiconductors by simple external light illumination.

Advantages:

Technology ID

2024-CHOI-70540

Category

Materials Science &
Nanotechnology/Nanomaterials
& Nanostructures
Computing/Photonic & Optical
Computing Technologies
Chemicals & Advanced
Materials/Materials Processing &
Manufacturing Technologies

Further information

Will Buchanan

wdbuchanan@prf.org

View online page



-Offers simplicity in preparation and device operation of optoelectronic devices

-Preserves the unique characteristics of MoSe₂

-Provides opportunities for designing new phototransistors and other 2D optoelectronic devices

-Could provide thinner channels in integrated circuits

Applications:

-Phototransistors

-Photodetectors

-Memristors

-LEDs

-Displays

TRL: 4

Intellectual Property:

Provisional-Gov. Funding, 2024-03-08, United States

Utility-Gov. Funding, 2025-03-06, United States

Keywords: catalysts, Chemical Engineering, Materials and Manufacturing, Toluene methylation, Xylene, Zeolites